

TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

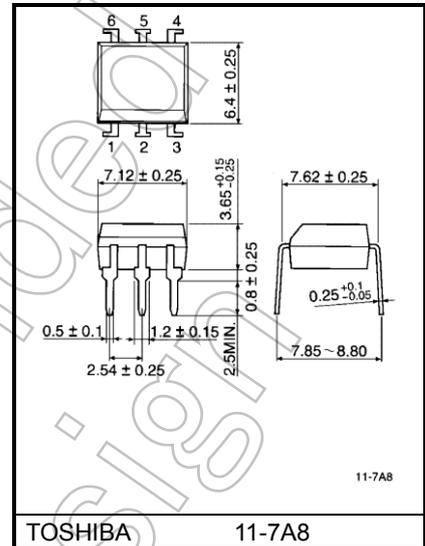
TLP371, TLP372

Programmable Controllers
Telecommunication
Solid State Relay

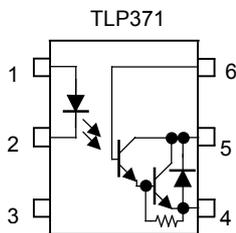
Unit: mm

The TOSHIBA TLP371 and TLP372 consists of a gallium arsenide infrared emitting diode optically coupled to a Darlington connected photo-transistor which has an integrated base-emitter resistor to optimize switching speed and elevated temperature characteristics in a six lead plastic DIP package. TLP372 has no-base internal connection for high-EMI environments.

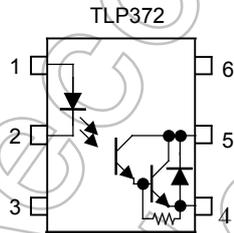
- Current transfer ratio : 1000% (min)
- Isolation voltage : 5000 Vrms (min)
- UL recognized : UL1577, file no. E67349
- cUL approved(TLP371): CSA Component Acceptance Service No. 5A
File No.E67349
- CQC approved(TLP371): GB4943.1,GB8898 Japan Factory



Pin Configurations (top view)



- 1 : Anode
- 2 : Cathode
- 3 : NC
- 4 : Emitter
- 5 : Collector
- 6 : Base



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Start of commercial production
1986-03

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	I_F	60	mA
	Forward current derating (Ta ≥ 39°C)	$\Delta I_F/^\circ\text{C}$	-0.7	mA/°C
	Peak forward current (100 μs pulse, 100 pps)	I_{FP}	1	A
	Reverse voltage	V_R	5	V
	Diode power dissipation	P_D	70	mW
	Diode power dissipation derating (Ta ≥ 39 °C)	$\Delta P_D/^\circ\text{C}$	-0.81	mW/°C
	Junction temperature	T_j	125	°C
Detector	Collector-emitter voltage	V_{CEO}	300	V
	Collector-base voltage (TLP371)	V_{CBO}	300	V
	Emitter-collector voltage	V_{ECO}	0.3	V
	Emitter-base voltage (TLP371)	V_{EBO}	7	V
	Collector current	I_C	150	mA
	Power dissipation	P_C	300	mW
	Power dissipation derating (Ta ≥ 25°C)	$\Delta P_C/^\circ\text{C}$	-3.0	mW/°C
	Junction temperature	T_j	125	°C
Storage temperature range		T_{stg}	-55 to 125	°C
Operating temperature range		T_{opr}	-55 to 100	°C
Lead soldering temperature (10 s)		T_{sol}	260	°C
Total package power dissipation		P_T	350	mW
Total package power dissipation derating (Ta ≥ 25°C)		$\Delta P_T/^\circ\text{C}$	-3.5	mW/°C
Isolation voltage (AC, 60 s, R.H. ≤ 60%) (Note 1)		BV_S	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: Device considered a two terminal device: Pins 1, 2 and 3 shorted together and pins 4,5 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Typ.	Max	Unit
Supply voltage	V_{CC}	—	—	200	V
Forward current	I_F	—	16	25	mA
Collector current	I_C	—	—	120	mA
Operating temperature	T_{opr}	-25	—	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0 \text{ V}, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 0.1 \text{ mA}$	300	—	—	V
	Emitter-collector breakdown voltage	$V_{(BR)ECO}$	$I_E = 0.1 \text{ mA}$	0.3	—	—	V
	Collector-base breakdown voltage (TLP371)	$V_{(BR)CBO}$	$I_C = 0.1 \text{ mA}$	300	—	—	V
	Emitter-base breakdown voltage (TLP371)	$V_{(BR)EBO}$	$I_E = 0.1 \text{ mA}$	7	—	—	V
	Collector dark current	I_{CEO}	$V_{CE} = 200 \text{ V}$	—	10	200	nA
			$V_{CE} = 200 \text{ V}, T_a = 85 \text{ }^\circ\text{C}$	—	—	20	μA
	Collector dark current (TLP371)	I_{CER}	$V_{CE} = 200 \text{ V}, T_a = 85 \text{ }^\circ\text{C}$ $R_{BE} = 10 \text{ M}\Omega$	—	0.5	10	μA
	Collector dark current (TLP371)	I_{CBO}	$V_{CB} = 200 \text{ V}$	—	0.1	—	nA
	DC forward current gain (TLP371)	h_{FE}	$V_{CE} = 5 \text{ V}, I_C = 10 \text{ mA}$	—	7000	—	—
	Capacitance (collector to emitter)	C_{CE}	$V = 0 \text{ V}, f = 1 \text{ MHz}$	—	10	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Current transfer ratio	I_C/I_F	$I_F = 1 \text{ mA}, V_{CE} = 1 \text{ V}$	1000	4000	—	%
Saturated CTR	$I_C/I_{F(sat)}$	$I_F = 10 \text{ mA}, V_{CE} = 1 \text{ V}$	500	—	—	%
Base photo-current (TLP371)	I_{PB}	$I_F = 1 \text{ mA}, V_{CB} = 1 \text{ V}$	—	6	—	μA
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 10 \text{ mA}, I_F = 1 \text{ mA}$	—	—	1.0	V
		$I_C = 100 \text{ mA}, I_F = 10 \text{ mA}$	0.3	—	1.2	

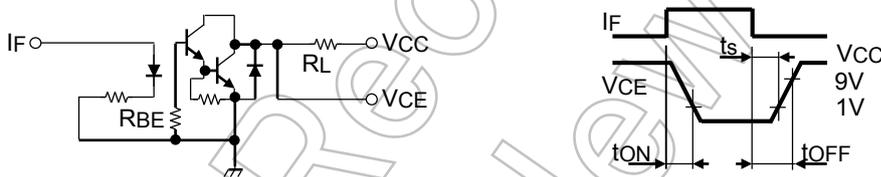
Isolation Characteristics (Ta = 25°C)

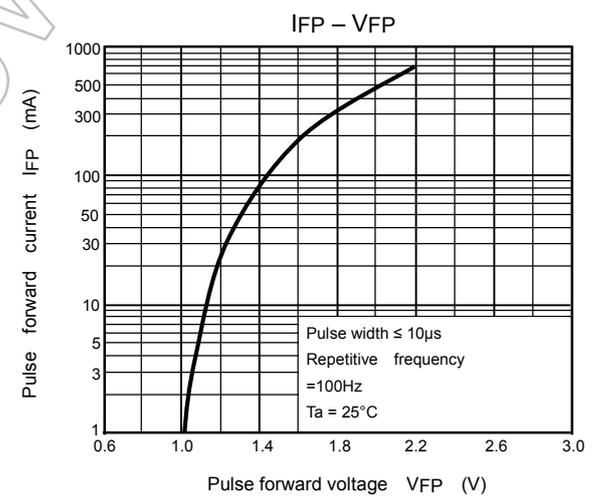
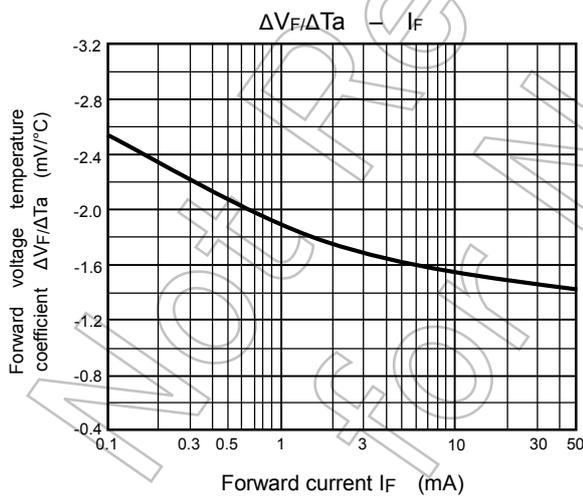
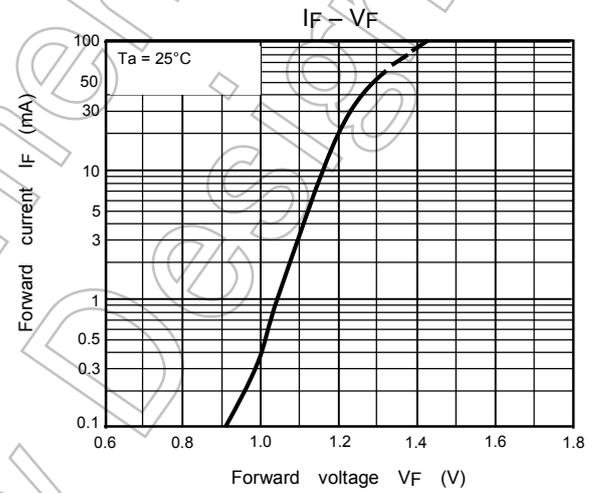
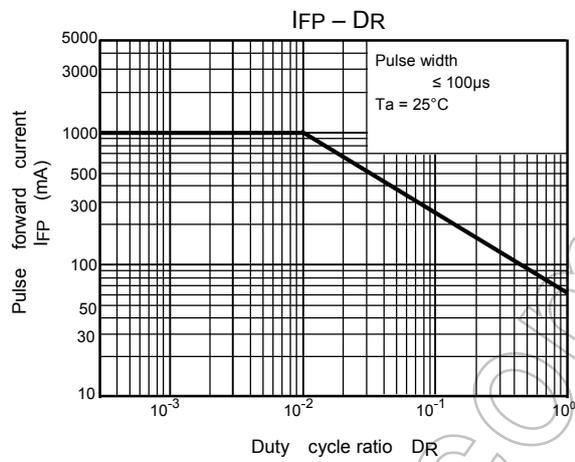
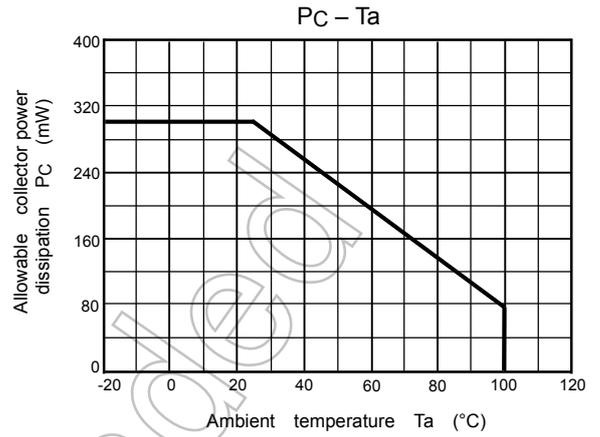
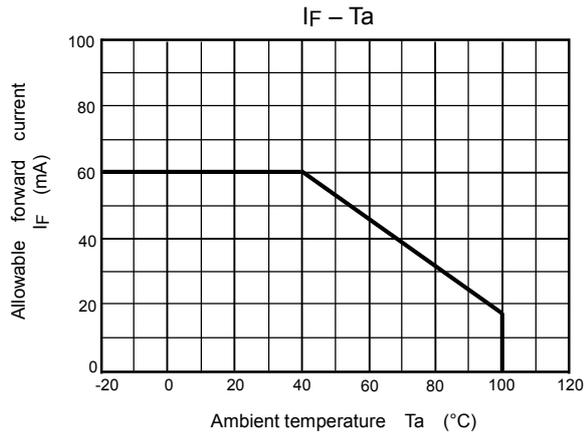
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance (input to output)	C _S	V _S = 0 V, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	—	Ω
Isolation voltage	BV _S	AC, 60 s	5000	—	—	V _{rms}
		AC, 1 s, in oil	—	10000	—	
		DC, 60 s, in oil	—	10000	—	V _{dc}

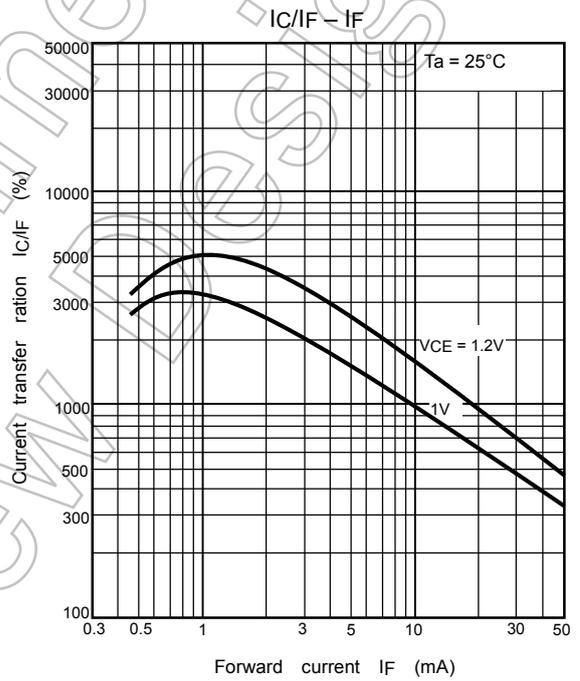
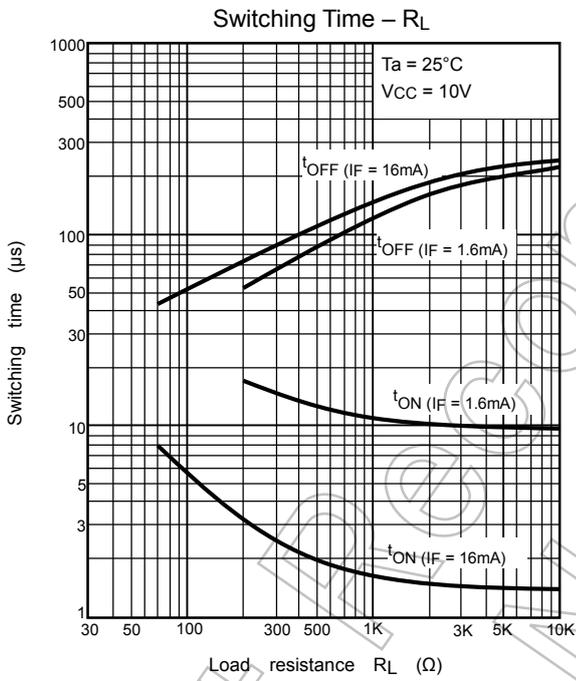
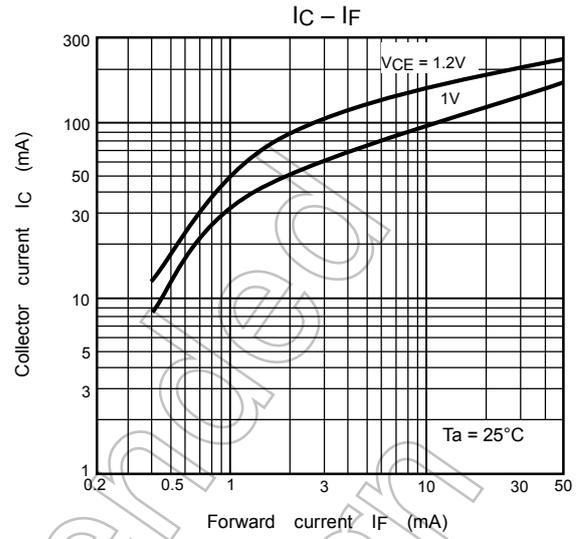
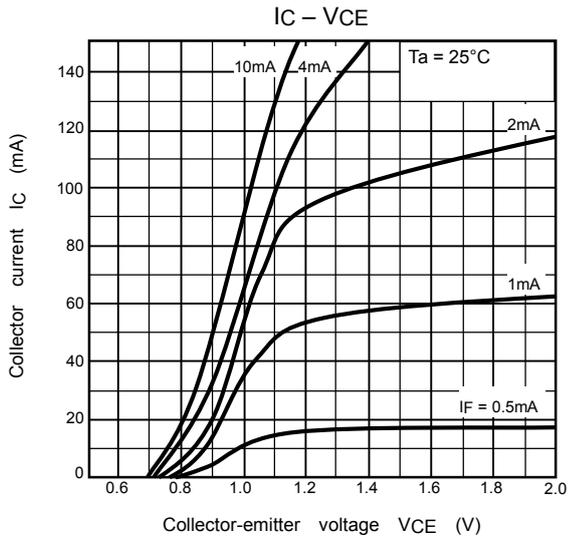
Switching Characteristics (Ta = 25°C)

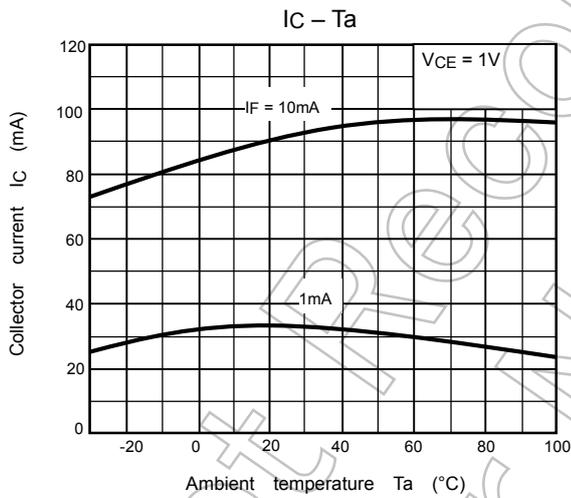
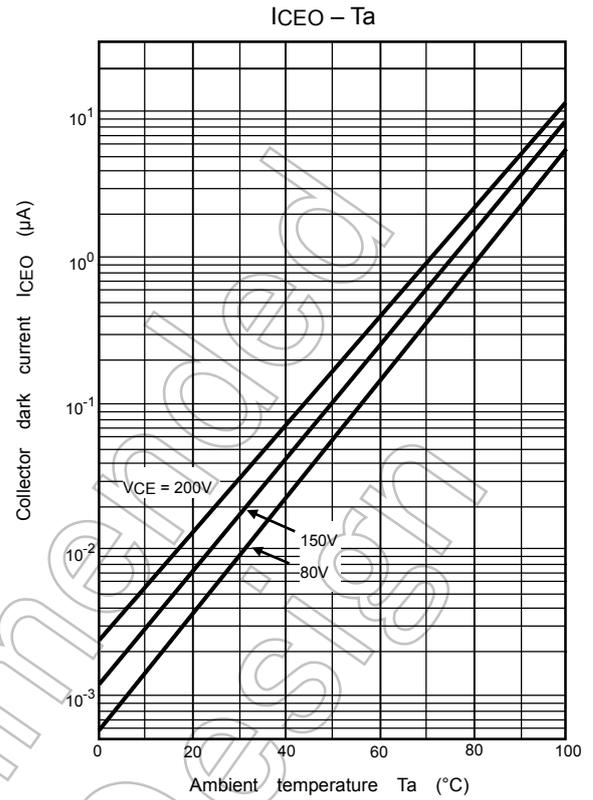
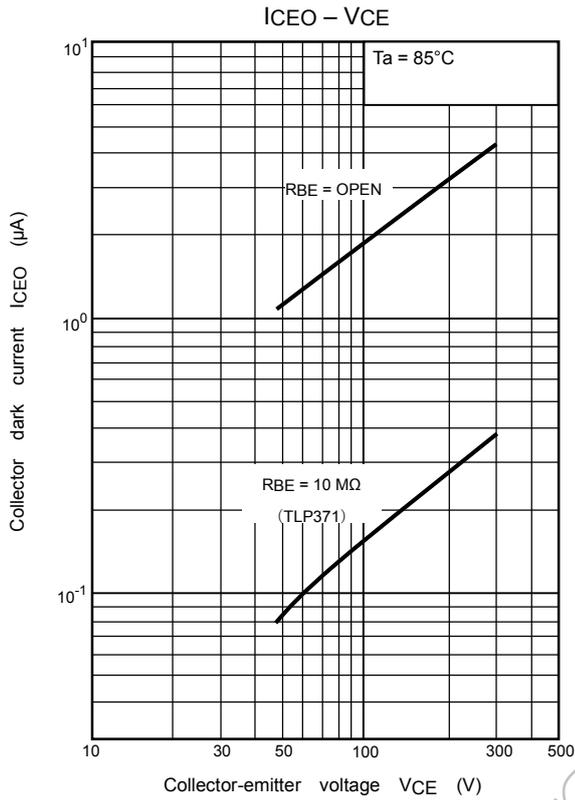
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Rise time	t _r	V _{CC} = 10 V I _C = 10 mA R _L = 100 Ω	—	40	—	μs
Fall time	t _f		—	15	—	
Turn-on time	t _{on}		—	50	—	
Turn-off time	t _{off}		—	15	—	
Turn-on time	t _{ON}	R _L = 180 Ω R _{BE} = OPEN V _{CC} = 10 V, I _F = 16 mA (Fig.1)	—	3	—	μs
Storage time	t _s		—	45	—	
Turn-off time	t _{OFF}		—	90	—	
Turn-on time	t _{ON}	R _L = 180 Ω R _{BE} = 10 MΩ (TLP371) V _{CC} = 10 V, I _F = 16 mA (Fig.1)	—	5	—	μs
Storage time	t _s		—	40	—	
Turn-off time	t _{OFF}		—	80	—	

Fig.1: Switching time test circuit









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